MONOE122; M€100E122

5V ECL 9-Bit Buffer

Description

The MC10E/100E122 is a 9-bit buffer. The device contains nine non-inverting buffer gates.

The 100 Series contains temperature compensation.

Features

- 500 ps Max. Propagation Delay
- PECL Mode Operating Range: V_{CC} = 4.2 V to 5.7 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -4.2 V to -5.7 V
- Internal Input 50 K Ω Pulldown Resistors
- ESD Protection: Human Body Model; > 2 kV, Machine Model; > 200 V
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level:

Pb = 1 Pb-Free = 3

For Additional Information, see Application Note AND8003/D

- Flammability Rating: UL 94 V-0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 111 devices
- Pb-Free Packages are Available*



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PLCC-28 FN SUFFIX CASE 776

MARKING DIAGRAMS



A = Assembly Location

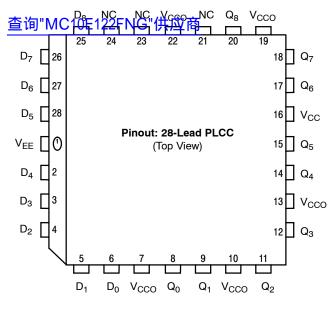
WL = Wafer Lot YY = Year WW = Work Week

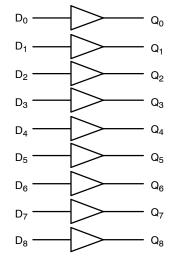
G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.





Warning: All V_{CC} , V_{CCO} , and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

Figure 1. Logic Diagram and Pinout Assignment

Figure 2. Logic Diagram

Table 1. PIN DESCRIPTION

PIN	FUNCTION					
D ₀ – D ₈	ECL Data Inputs					
Q ₀ – Q ₈	ECL Data Outputs					
V _{CC} , V _{CCO}	Positive Supply					
V _{EE}	Negative Supply					
NC	No Connect					

Table 2. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{array}{c} V_{I}\!\leq\!V_{CC} \\ V_{I}\!\geq\!V_{EE} \end{array}$	6 -6	V V
I _{out}	Output Current	Continuous Surge		50 100	mA mA
T _A	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ _{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	PLCC-28 PLCC-28	63.5 43.5	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction-to-Case)	Standard Board	PLCC-28	22 to 26	°C/W
T _{sol}	Wave Solder Pb Pb-Free			265 265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

^{*} All V_{CC} and V_{CCO} pins are tied together on the die.

THE BARDES PECHING CHARACTERISTICS VCCx= 5.0 V; VEE= 0.0 V (Note 1)

		0°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		41	49		41	49		41	49	mA
V _{OH}	Output HIGH Voltage (Note 2)	3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2)	3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage	3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
V _{IL}	Input LOW Voltage	3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
I _{IH}	Input HIGH Current			200			200			200	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.3	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary –0.46 V / +0.06 V.
- 2. Outputs are terminated through a 50 ohm resistor to V_{CC} 2.0 V.

Table 4. 10E SERIES NECL DC CHARACTERISTICS V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 3)

		0°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		41	49		41	49		41	49	mA
V _{OH}	Output HIGH Voltage	-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage	-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
V _{IH}	Input HIGH Voltage	-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
V _{IL}	Input LOW Voltage	-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
I _{IH}	Input HIGH Current			200			200			200	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.065		0.3	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 3. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary –0.46 V / +0.06 V.
- 4. Outputs are terminated through a 50 ohm resistor to V_{CC} 2.0 V.

TO SEPIES PECL DOCKHARACTERISTICS VCCx= 5.0 V; VEE= 0.0 V (Note 5)

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		41	49		41	49		47	57	mA
V _{OH}	Output HIGH Voltage	3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage	3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V _{IH}	Input HIGH Voltage	3835	3975	4120	3835	3975	4120	3835	3975	4120	mV
V _{IL}	Input LOW Voltage	3190	3355	3525	3190	3355	3525	3190	3355	3525	mV
I _{IH}	Input HIGH Current			200			200			200	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 5. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary -0.46~V / +0.8~V.
- 6. Outputs are terminated through a 50 ohm resistor to V_{CC} 2.0 V.

Table 6. 100E SERIES NECL DC CHARACTERISTICS V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 7)

		0°C			25°C			85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		41	49		41	49		47	57	mA
V _{OH}	Output HIGH Voltage	-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V _{OL}	Output LOW Voltage	-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V _{IH}	Input HIGH Voltage	-1165	-1025	-880	-1165	-1025	-880	-1165	-1025	-880	mV
V _{IL}	Input LOW Voltage	-1810	-1645	-1475	-1810	-1645	-1475	-1810	-1645	-1475	mV
I _{IH}	Input HIGH Current			200			200			200	μΑ
I _{IL}	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 7. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary -0.46~V / +0.8~V.
- 8. Outputs are terminated through a 50 ohm resistor to V_{CC} 2.0 V.

Table 7, AC CHARACTERISTICS V_{CCx}= 5.0 V; V_{EE}= 0.0 V or V_{CCx}= 0.0 V; V_{EE}= -5.0 V (Note 7)

			0°C		25°C		85°C				
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{MAX}	Maximum Toggle Frequency		800			800			800		MHz
t _{PLH}	Propagation Delay to Output										ps
t _{PHL}	D to Q	150	350	500	150	350	500	150	350	500	
t _{SKEW}	Within-Device Skew										ps
	D to Q (Note 10)		75			75			75		
t _{JITTER}	Random Clock Jitter (RMS)		< 1			< 1			< 1		ps
t _r	Rise/Fall Times										ps
t _f	(20 - 80%)	300	425	800	300	425	800	300	425	800	

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

- 9. 10 Series: V_{EE} can vary -0.46 V / +0.06 V. 100 Series: V_{EE} can vary -0.46 V / +0.8 V.
- 10. Within-device skew is defined as identical transitions on similar paths through a device.
- 11. Devices are designed to meet the AC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

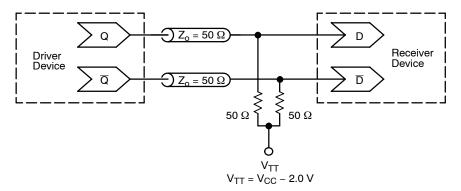


Figure 3. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

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Device	Package	Shipping [†]
MC10E122FN	PLCC-28	37 Units / Rail
MC10E122FNG	PLCC-28 (Pb-Free)	37 Units / Rail
MC10E122FNR2	PLCC-28	500 / Tape & Reel
MC10E122FNR2G	PLCC-28 (Pb-Free)	500 / Tape & Reel
MC100E122FN	PLCC-28	37 Units / Rail
MC100E122FNR2	PLCC-28	500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Resource Reference of Application Notes

AN1405/D - ECL Clock Distribution Techniques

AN1406/D - Designing with PECL (ECL at +5.0 V)

AN1503/D - ECLinPS™ I/O SPICE Modeling Kit

AN1504/D - Metastability and the ECLinPS Family
AN1568/D - Interfacing Between LVDS and ECL

AN1672/D - The ECL Translator Guide

AND8001/D - Odd Number Counters Design

AND8002/D - Marking and Date Codes

AND8020/D - Termination of ECL Logic Devices

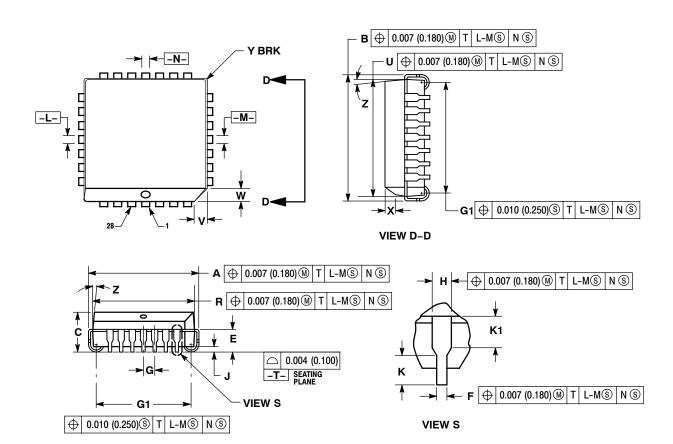
AND8066/D - Interfacing with ECLinPS

AND8090/D - AC Characteristics of ECL Devices

查询"MC10E122FNG"供应商

PACKAGE DIMENSIONS

PLCC-28 **FN SUFFIX** PLASTIC PLCC PACKAGE CASE 776-02 ISSUE E



NOTES:

- DATUMS -L-, -M-, AND -N- DETERMINED
 WHERE TOP OF LEAD SHOULDER EXITS
- WHERE TOP OF LEAD SHOULDER EXITS
 PLASTIC BODY AT MOLD PARTING LINE.

 2. DIMENSION G1, TRUE POSITION TO BE
 MEASURED AT DATUM -T-, SEATING PLANE.

 3. DIMENSIONS R AND U DO NOT INCLUDE
 MOLD FLASH, ALLOWABLE MOLD FLASH IS
 0.010 (0.250) PER SIDE.

 4. DIMENSIONING AND TOLERANCING PER
 ANNUAL MALANAL AND AND TOLERANCING PER
- ANSI Y14.5M, 1982. 5. CONTROLLING DIMENSION: INCH.
- 6. THE PACKAGE TOP MAY BE SMALLER THAN THE PACKAGE BOTTOM BY UP TO 0.012 (0.300). DIMENSIONS R AND U ARE DETERMINED AT THE OUTERMOST DE LEMINIED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY EXCLUSIVE OF MOLD FLASH, TIE BAR BURRS, GATE BURRS AND INTERLEAD FLASH, BUT INCLUDING ANY MISMATCH BETWEEN THE TOP AND BOTTOM OF THE BLASTIC BODY PLASTIC BODY.
- 7. DIMENSION H DOES NOT INCLUDE DAMBAR PROTRUSION OR INTRUSION. THE DAMBAR PROTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE GREATER THAN 0.037 (0.940). THE DAMBAR INTRUSION(S) SHALL NOT CAUSE THE H DIMENSION TO BE SMALLER THAN 0.025 (0.635).

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.485	0.495	12.32	12.57
В	0.485	0.495	12.32	12.57
c	0.165	0.180	4.20	4.57
Е	0.090	0.110	2.29	2.79
F	0.013	0.019	0.33	0.48
G	0.050	BSC	1.27	BSC
Н	0.026	0.032	0.66	0.81
J	0.020		0.51	
K	0.025		0.64	
R	0.450	0.456	11.43	11.58
J	0.450	0.456	11.43	11.58
٧	0.042	0.048	1.07	1.21
W	0.042	0.048	1.07	1.21
X	0.042	0.056	1.07	1.42
Υ	-	0.020		0.50
Z	2 °	10°	2 °	10°
G1	0.410	0.430	10.42	10.92
K1	0.040		1.02	

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